








	<p>IPD70N04S3-07</p>
	<p>Hersteller-Teilenummer: IPD70N04S3-07</p> <p>Hersteller / Marke: International Rectifier (Infineon Technologies)</p> <p>Teil der Beschreibung: MOSFET N-CH 40V 82A TO252-3</p> <p>Datenblätter:  IPD70N04S3-07.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 45420 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPD70N04S3-07
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 40V 82A TO252-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	45420 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	79W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	82A (Tc)
Rds On (Max) @ Id, Vgs	6 mOhm @ 70A, 10V
VGS (th) (Max) @ Id	4V @ 50µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2700pF @ 25V
Verpackung	Tape & Reel (TR)

IPD70N04S3-07 ist neu im Original, Suche IPD70N04S3-07 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD70N04S3-07 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD70N04S3-07: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPD65R950CFDBTMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 650V 3.9A TO-252</p>	 <p>IPD70N03S4L-04 International Rectifier (Infineon Technologies) IPD70N03S4L-04 Infineon Technologies</p>	 <p>IPD65R950CFDATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 650V 3.9A TO-252</p>	 <p>IPD70N10S3L-12 International Rectifier (Infineon Technologies) IPD70N10S3L-12 Infineon Technologies</p>
 <p>IPD70N10S312ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 100V 70A TO252-3</p>	 <p>IPD70N10S3-12 VBsemi IPD70N10S3-12 VBsemi</p>	 <p>IPD70N10S3L12ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 100V 70A TO252-3</p>	 <p>IPD70N03S4L04ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 30V 70A TO252-3</p>

heiße Teile

Mehr

⊗ IPD60R520C6	↔ IPD60R520CP	⇒ IPD60R600C6	D IPD60R600CP	↔ IPD60R600E6
⊣ IPD60R600P6	⊗ IPD60R750E6	D IPD60R800CE	⇒ IPD60R950C6	↔ IPD640N06LG
⊗ IPD64CN10NG	⊣ IPD65R1K4C6	⊗ IPD65R250C6	↔ IPD65R250E6	↔ IPD65R380C6
D IPD65R380E6	⊗ IPD65R420CFD	⊣ IPD65R420CFDA	⊗ IPD65R600C6	↔ IPD65R600E6
⇒ IPD65R660CFD	↔ IPD65R950C6	⊗ IPD65R950CFD	⊣ IPD70N03S4L-04	↔ IPD70N03S4L04XT
↔ IPD70N10S3-12	⇒ IPD70N10S3L-12	D IPD70P04P4-09	⊗ IPD70P04P4L-08	⊣ IPD75N04S4-06
⊗ IPD78CN10NG	D IPD800N06NG	⇒ IPD80N04S3-06	↔ IPD80N04S3-06B	↔ IPD80N06S3-09
⊣ IPD80P03P4L-07	⊗ IPD80R1K0CE	↔ IPD80R1K4CE	⇒ IPD85P04P4L-06	↔ IPD90N03S4L-02
⊗ IPD90N03S4L-03	⊣ IPD90N04S03-04	⊗ IPD90N04S3-04	D IPD90N04S3-H4	↔ IPD90N04S4-02
↔ IPD90N04S4-03	⊗ IPD90N04S4-04	⊣ IPD90N04S4-05	⊗ IPD90N04S4L-04	↔ IPD90N06S3-06

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited